

Trans MOSFET N-CH 600V 20A

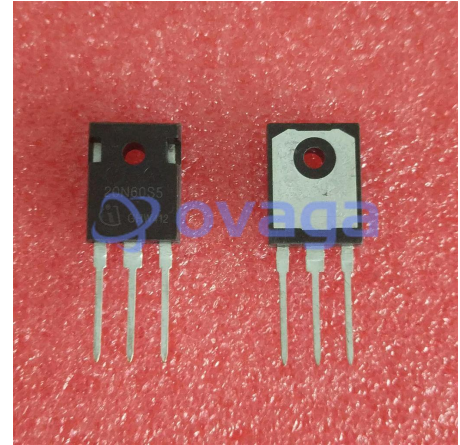
Manufacturers [Infineon Technologies Corporation](#)

Package/Case TO-247

Product Type Transistors

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for SPW20N60S5 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

SPW20N60S5 is a power MOSFET transistor manufactured by Infineon Technologies.

Features

It has a drain-source voltage rating of 600V.

The maximum continuous drain current is 20A.

It has a low on-state resistance ($R_{DS(on)}$) of 0.2 ohms.

The gate threshold voltage is typically 4V.

It has a fast switching speed and low capacitance.

Application

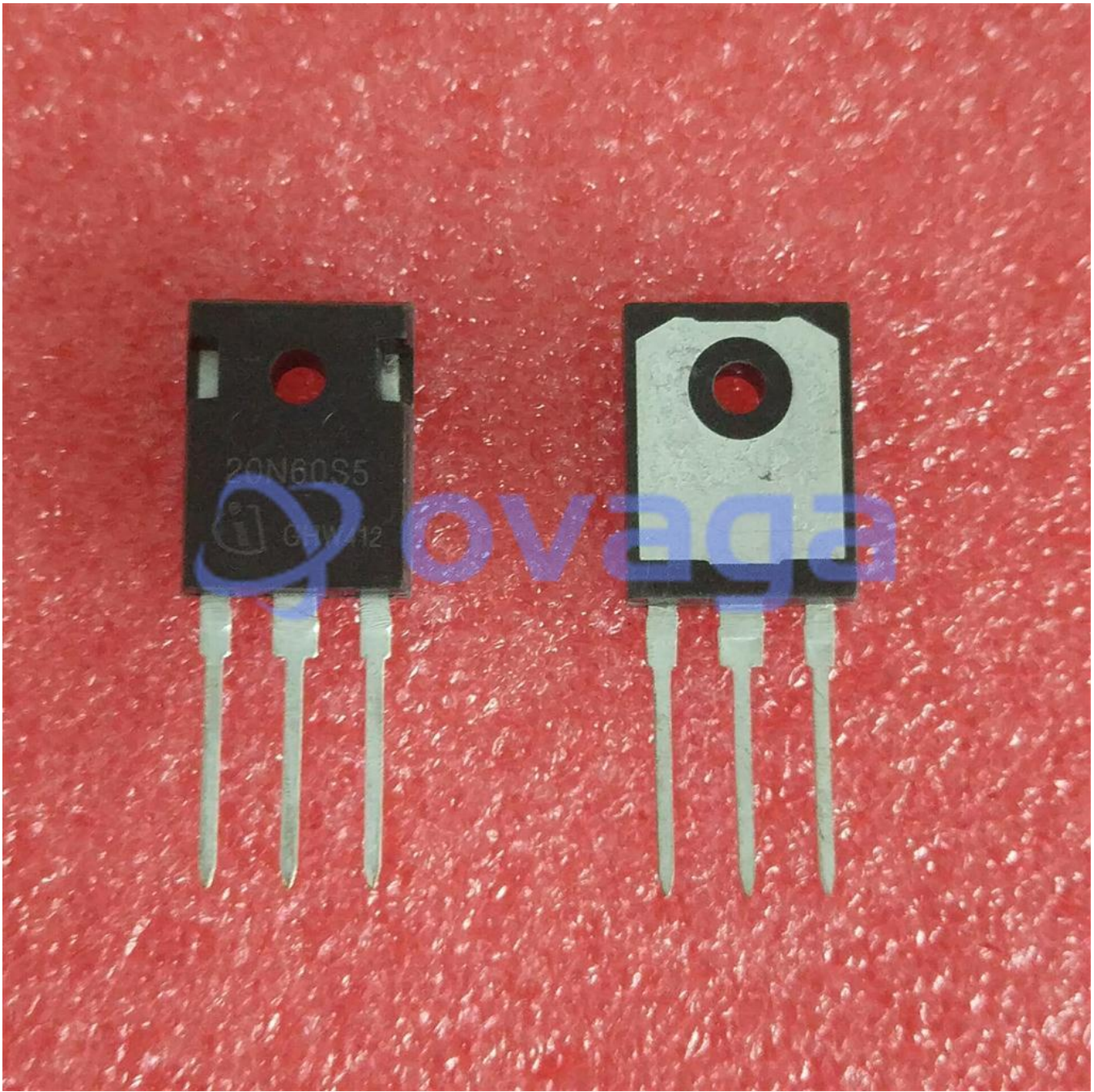
Switch mode power supplies (SMPS)

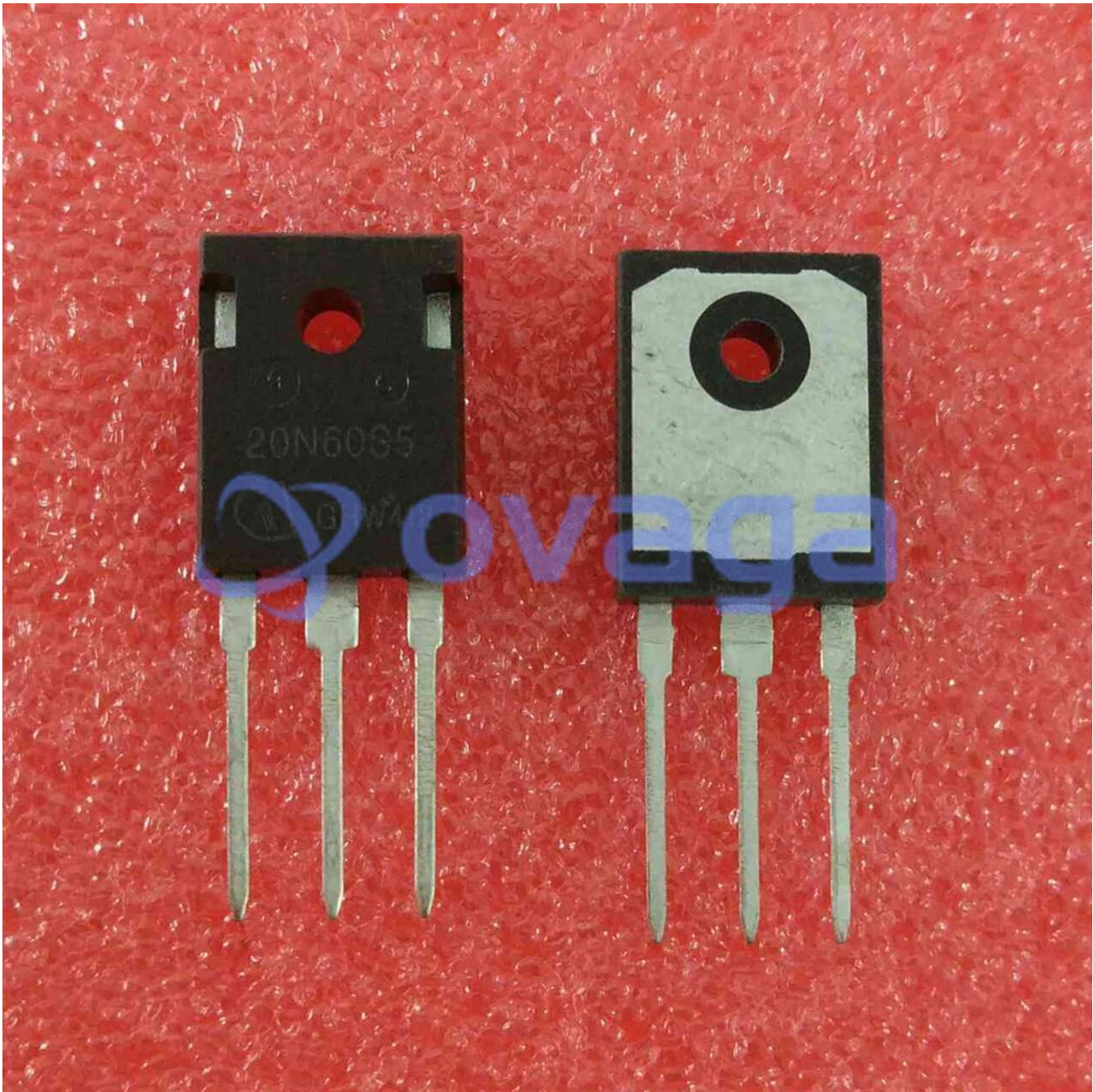
Power factor correction (PFC)

Motor control

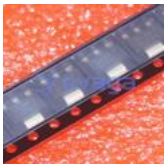
Lighting ballasts

Audio amplifiers





Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



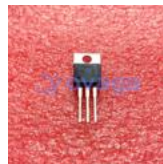
[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

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TO-220AB



[SPP07N60S5](#)

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P-TO220-3-1



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[IRF640NSPBF](#)

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PAK-3



[SPD03N60S5](#)

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TO-252



[SPP20N60CFD](#)

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TO-220AB